2015 1

Course Title	()	()	Nanodevice Engineering
course ritte			
() Lecturer	()	/ / (Course No. /)	006788/ /3
(/HP) Contact No.		/ (Class Hour/Venue)	
(Course Prerequisite)		(Target Student)	3~4th grade
E-mail (E-mail Address)		/Office Hour (Office/Office Hour)	10:00 am ~ 8:00 pm
(Objectives)	7h PN junction, semiconductor 7h The purpose of this class is to understand the basic productor, displays, optoelectronics, or general esemiconductor devices are very important for those job	electronic fields are strongly encoura	
CQI (Continuous Quality Improvement Plan)			
(Text book & References)	Semiconductor Physics and Device Author: Donald A. Neamen :	s (basic principles) McGRAW-HILL	-Third edition
(Assignment book)			
(Lecture Methods)	Powerpoint presentation. The lec	ture will be given in l	English ()
(Assignment)	1. 2. 3. 4. 5.		
(Reading Materials)			
가 (Course Grading)	[7t] (%) : 30, (30)%, (40)%,	(%) : 40, 가 가 ()%, (10	(%): 20, (%): 10,)%, (20)%
(Etc.)	The lecture will be given in Eng	lish ()	

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(Week)	(Course Contents)	(Etc.)	
1	Introduction Ch.1 Crystal Structure of Solids		
2	Ch. 2 Introduction to Quantum Mechanics		
3	Ch.3 Introduction to the Quantum Theory of Soilds		
4	Ch.4 The semiconductor in Equilibrium		
5	Ch.4 The semiconductor in Equilibrium		
6	Ch.5 Carrier Transport Phenomena		
7	Ch.5 Carrier Transport Phenomena		
8	Midterm test		

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(Week)	(Course Contents)	(Etc.)	
9	Ch.6 Nonequilibrium Excess Carriers in Semiconductors		
10	Ch.7 The PN junction		
11	Ch.7 The PN junction		
12	Ch.8 The PN junction diode		
13	Ch.9 Metal Semiconductor and Semiconductor Heterojunctions		
14	Ch. Bipolar transistor, Basic MOSFET		
15	MOSFET transistors		
16	Final term test		

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	Students who require special assistance (including special needs students) may contact their professors during the first week of the semester to discuss issues related to attendance, lectures, assignments and exams and request learning assistance.
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(Addi ti onal Gui de1)	
가 2	
(Additional Guide2)	